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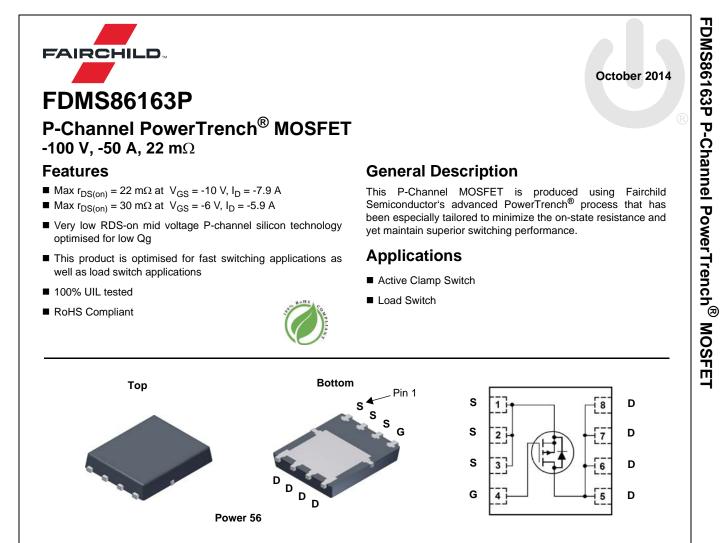


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## MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V <sub>DS</sub>	Drain to Source Voltage			-100	V	
V <sub>GS</sub>	Gate to Source Voltage			±25	V	
ID	Drain Current -Continuous T <sub>C</sub> =			-50		
	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	-7.9	Α	
	-Pulsed (Note			-100		
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	486	mJ	
P <sub>D</sub>	Power Dissipation	T <sub>C</sub> = 25 °C		104	W	
	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.5	VV	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C	

### **Thermal Characteristics**

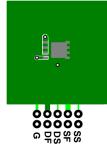
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.2	°C/W	]
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient (Note 1a)	50	C/VV	

## **Package Marking and Ordering Information**

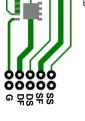
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86163P	FDMS86163P	Power 56	13 "	12 mm	3000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	cteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = -250 μA, V <sub>GS</sub> = 0 V	-100			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , referenced to 25 °C		-59		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \ \mu A$	-2	-2.8	-4	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_{.l}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , referenced to 25 °C		6.2		mV/°C	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -7.9 A		17.8	22		
		$V_{GS} = -6 \text{ V}, \text{ I}_{D} = -5.9 \text{ A}$		21.3	30	mΩ	
		V <sub>GS</sub> = -10 V, I <sub>D</sub> = -7.9 A,T <sub>J</sub> = 125 °C		29	36		
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -7.9 A		29		S	
C <sub>iss</sub> C <sub>oss</sub> C <sub>rss</sub>	Input Capacitance Output Capacitance Reverse Transfer Capacitance	V <sub>DS</sub> = -50 V, V <sub>GS</sub> = 0 V, f = 1 MHz		3070 501 21	4085 670 35	pF pF pF	
	-		0.4				
Rg	Gate Resistance		0.1	2.6	5.3	Ω	
Switching	g Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			17	30	ns	
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = -50 V, I <sub>D</sub> = -7.9 A,		8.8	18	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		33	53	ns	
t <sub>f</sub>	Fall Time	7		6.9	14	ns	
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } -10 V$		42	59	nC	
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } -6 V$ $V_{DD} = -50 V$ , $I_D = -7.9 A$		26	37	nC	
Q <sub>gs</sub>	Gate to Source Charge	I <sub>D</sub> = -7.9 A		11.8		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			7.1		nC	
Drain-Soເ	urce Diode Characteristics						
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = -7.9 A$ (Note 2)		-0.81	-1.3	V	
		$V_{GS} = 0 V, I_S = -2 A$ (Note 2)		-0.75	-1.2	v	
t <sub>rr</sub>	Reverse Recovery Time	– I <sub>F</sub> = -7.9 A, di/dt = 100 A/μs –		63	102	ns	
Q <sub>rr</sub>	Reverse Recovery Charge	$F = 1.3 \text{ A}, \text{ u/ul} = 100 \text{ A/}\mu\text{S}$		132	210	nC	

the user's board design.

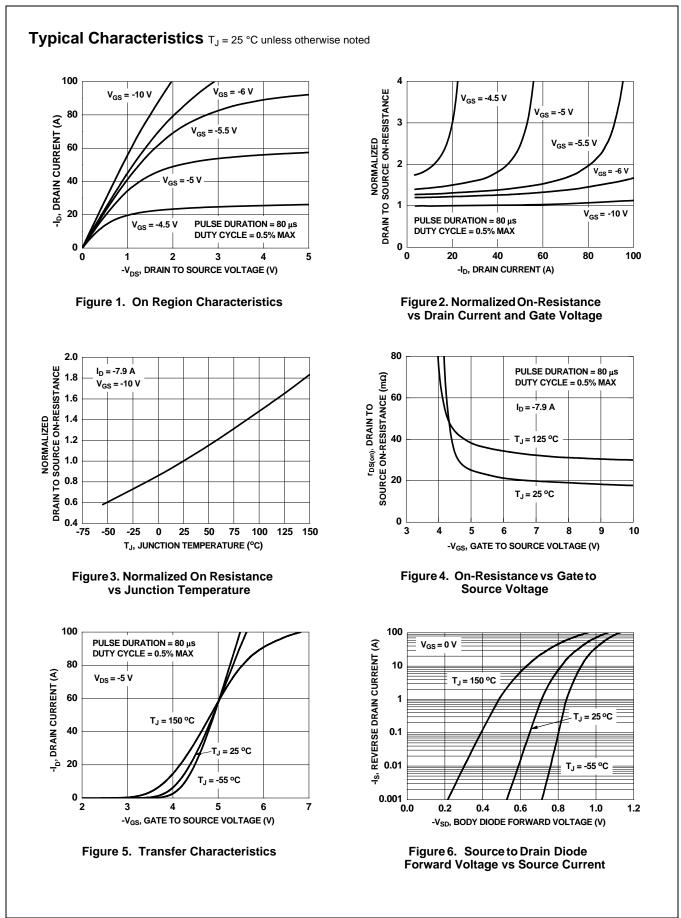


a) 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper

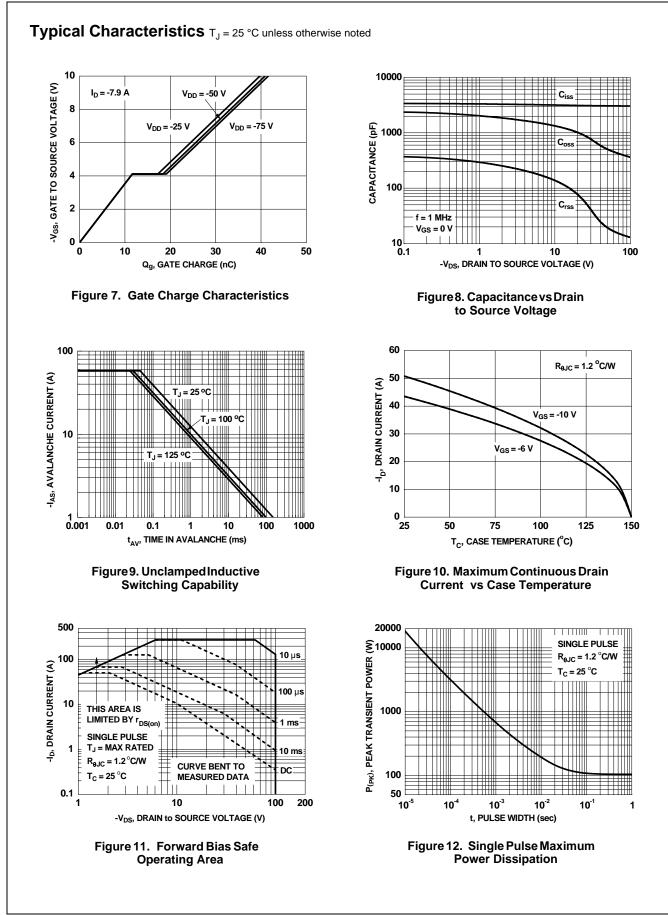


b) 125 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300  $\mu$ s, Duty cycle < 2.0%. 3. Starting T<sub>J</sub> = 25 °C; P-ch: L = 3 mH, I<sub>AS</sub> = -18 A, V<sub>DD</sub> = -100 V, V<sub>GS</sub> = -10 V. 100% test at L = 0.1 mH, I<sub>AS</sub> = -58 A. 4. Pulse Id refers to Figure.11 Forward Bias Safe Operation Area.

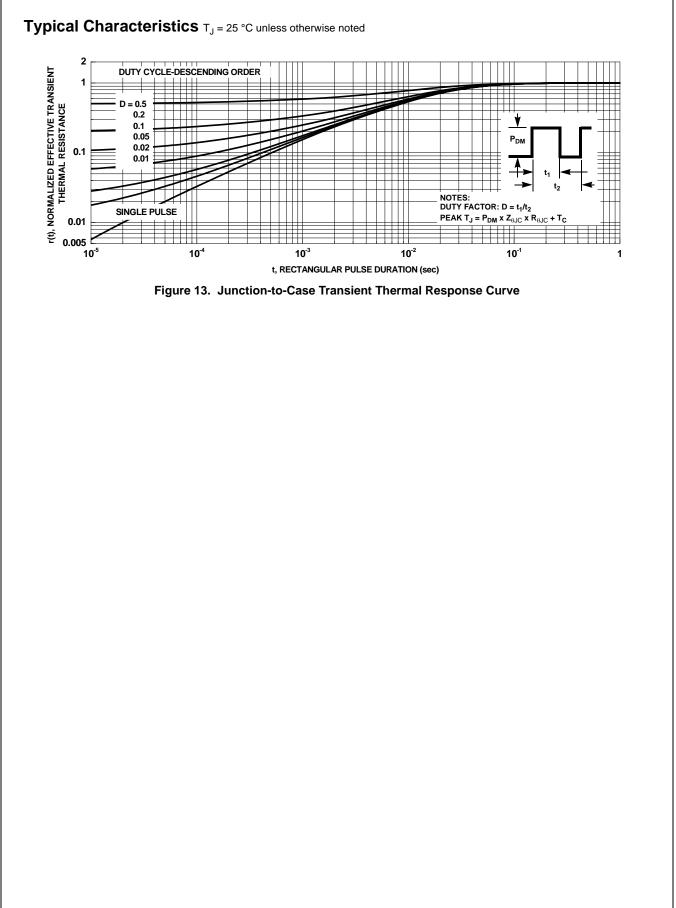


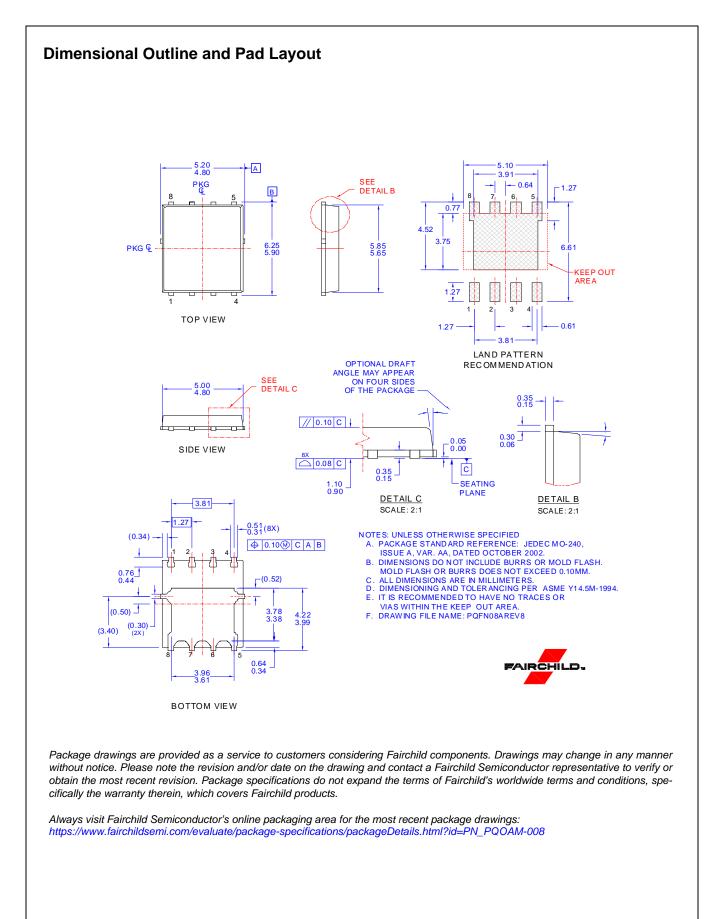


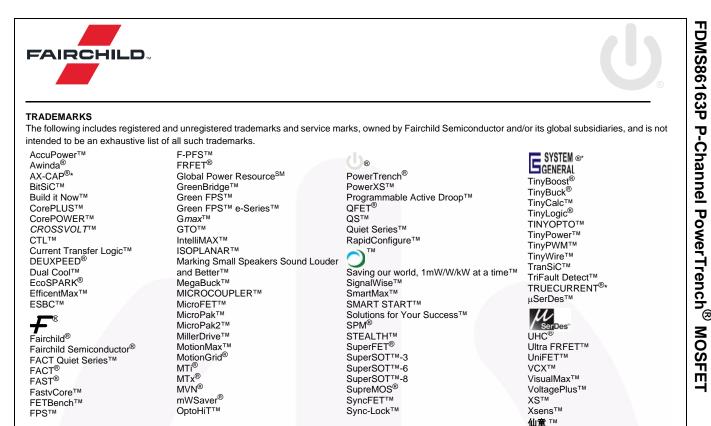


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4







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